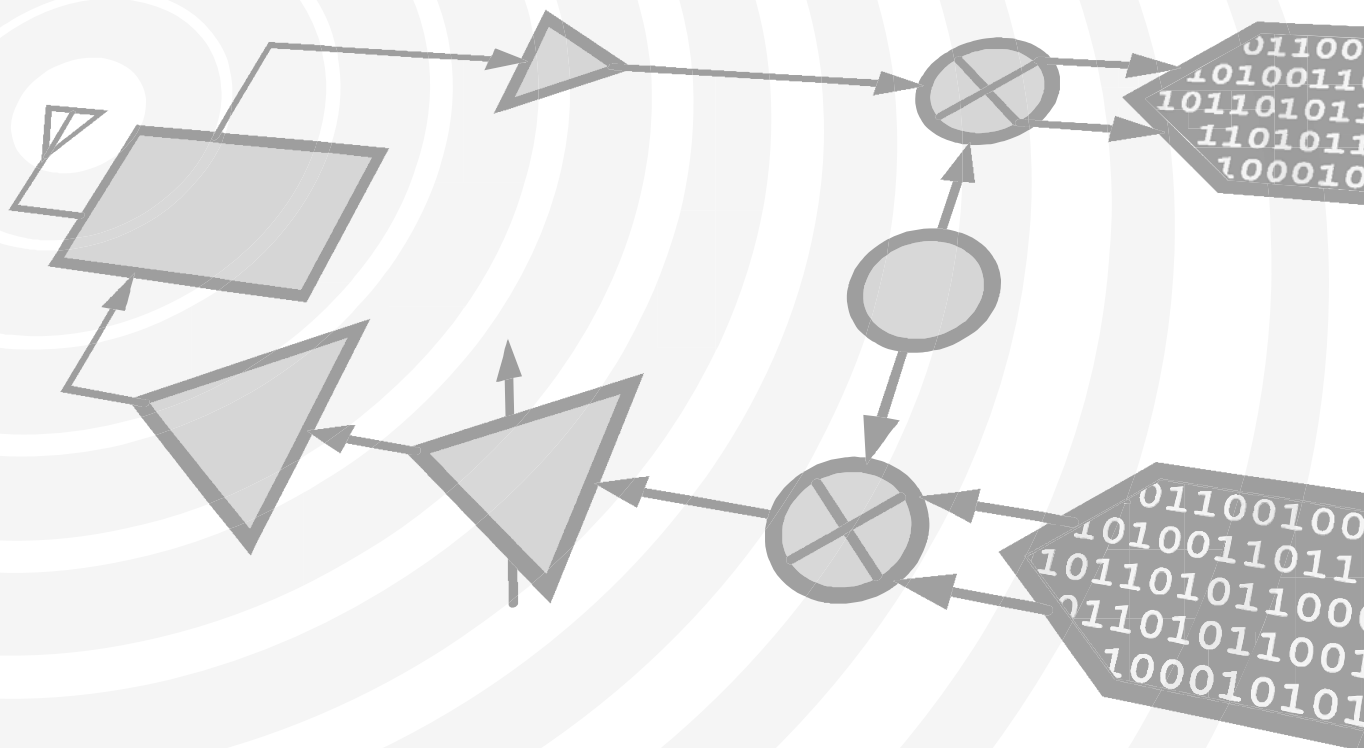




NO CONTENT ON THE ATTACHED DOCUMENT HAS CHANGED



THIS PAGE INTENTIONALLY LEFT BLANK



MICROWAVE CORPORATION v04.0811



HMC531LP5 / 531LP5E

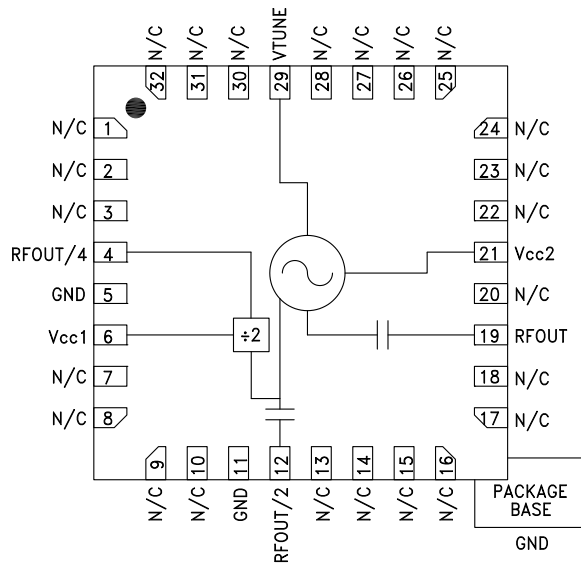
MMIC VCO w/ HALF FREQUENCY OUTPUT & DIVIDE-BY-4, 13.6 - 14.9 GHz

Typical Applications

Low noise MMIC VCO w/Half Frequency, Divide-by-4
Outputs for:

- VSAT Radio
- Point to Point/Multipoint Radio
- Test Equipment & Industrial Controls
- Military End-Use

Functional Diagram



Features

Dual Output: $F_o = 13.6 - 14.9$ GHz
 $F_o/2 = 6.8 - 7.45$ GHz

Pout: +7 dBm

Phase Noise: -110 dBc/Hz @100 kHz Typ.

No External Resonator Needed

32 Lead 5x5mm SMT Package: 25mm²

General Description

The HMC531LP5 & HMC531LP5E are GaAs InGaP Heterojunction Bipolar Transistor (HBT) MMIC VCOs. The HMC531LP5 & HMC531LP5E integrate resonators, negative resistance devices, varactor diodes and feature half frequency and divide-by-4 outputs. The VCO's phase noise performance is excellent over temperature, shock, and process due to the oscillator's monolithic structure. Power output is +7 dBm typical from a +5V supply voltage. The prescaler function can be disabled to conserve current if not required. The voltage controlled oscillator is packaged in a leadless QFN 5x5 mm surface mount package, and requires no external matching components.

Electrical Specifications, $T_A = +25^\circ\text{C}$, V_{cc1} , $V_{cc2} = +5\text{V}$

Parameter	Min.	Typ.	Max.	Units
Frequency Range		13.6 - 14.9		GHz
		6.8 - 7.45		GHz
Power Output				
RFOUT	+3		+10	dBm
RFOUT/2	+8		+14	dBm
RFOUT/4	-9		-3	dBm
SSB Phase Noise @ 100 kHz Offset, $V_{tune} = +5\text{V}$ @ RFOUT		-110		dBc/Hz
Tune Voltage	2		13	V
Supply Current	220	260	300	mA
Tune Port Leakage Current ($V_{tune} = 13\text{V}$)			10	μA
Output Return Loss		8		dB
Harmonics/Subharmonics				
1/2		25		dBc
3/2		35		dBc
2nd		18		dBc
3rd		40		dBc
Pulling (into a 2.0:1 VSWR)		5		MHz pp
Pushing @ $V_{tune} = 5\text{V}$		6		MHz/V
Frequency Drift Rate		1.2		MHz/ $^\circ\text{C}$

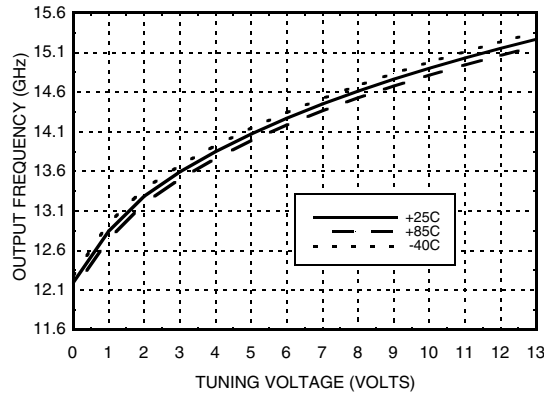
For price, delivery and to place orders: Hittite Microwave Corporation, 20 Alpha Road, Chelmsford, MA 01824

Phone: 978-250-3343 Fax: 978-250-3373 Order On-line at www.hittite.com

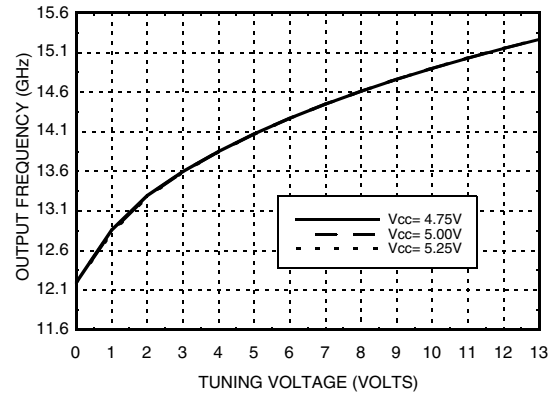
Application Support: Phone: 978-250-3343 or apps@hittite.com

MMIC VCO w/ HALF FREQUENCY OUTPUT & DIVIDE-BY-4, 13.6 - 14.9 GHz

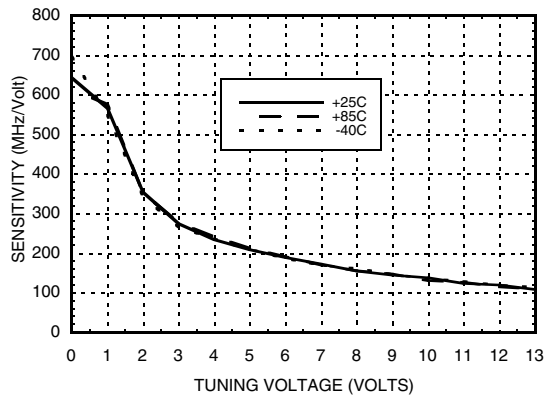
Frequency vs. Tuning Voltage, $V_{cc} = +5V$



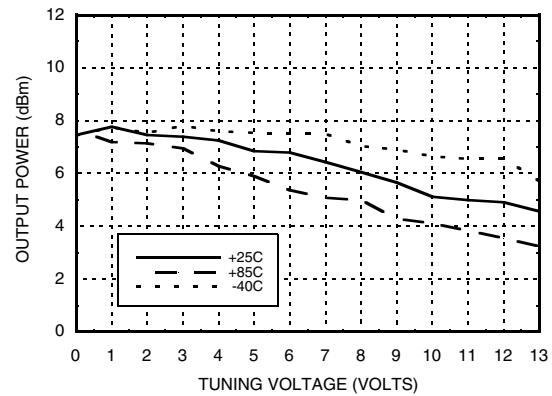
Frequency vs. Tuning Voltage, $T = 25^{\circ}C$



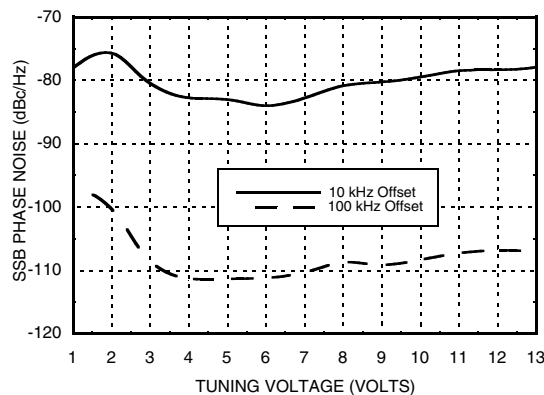
Sensitivity vs. Tuning Voltage, $V_{cc} = +5V$



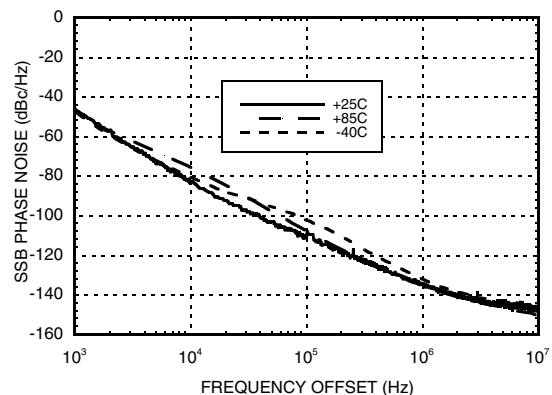
Output Power vs. Tuning Voltage, $V_{cc} = +5V$



SSB Phase Noise vs. Tuning Voltage



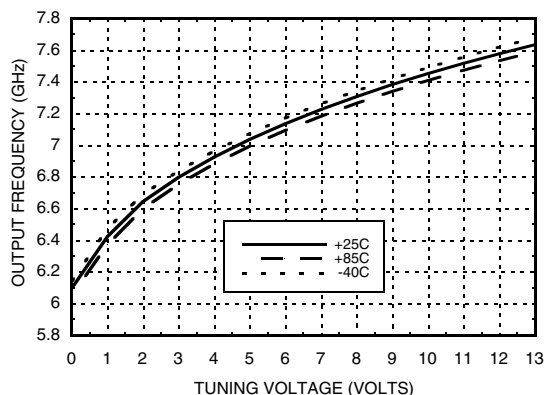
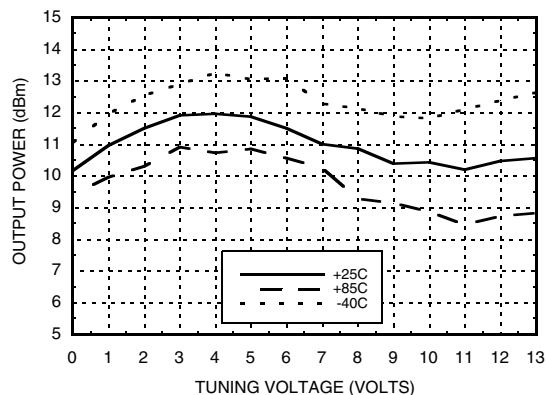
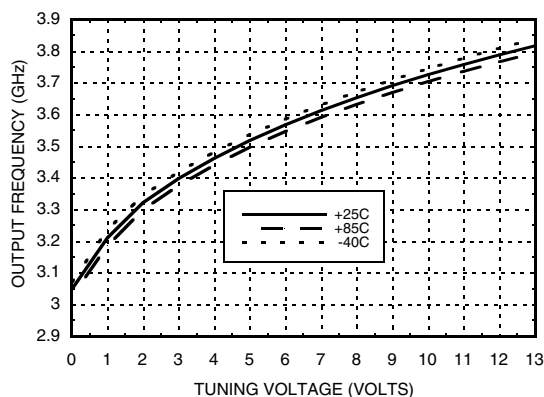
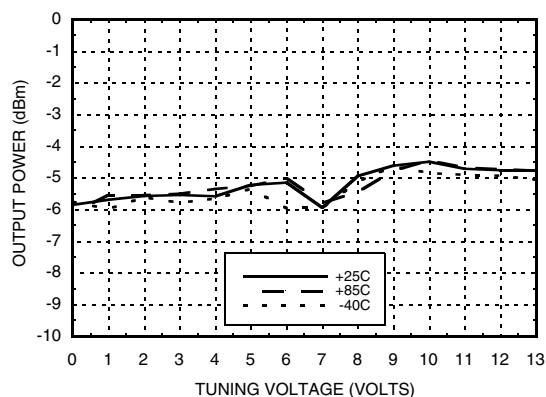
SSB Phase Noise @ $V_{tune} = +5V$





MICROWAVE CORPORATION

v04.0811

**HMC531LP5 / 531LP5E****MMIC VCO w/ HALF FREQUENCY OUTPUT
& DIVIDE-BY-4, 13.6 - 14.9 GHz****RFOUT/2 Frequency
vs. Tuning Voltage, Vcc= +5V****RFOUT/2 Output Power
vs. Tuning Voltage, Vcc= +5V****Divide-by-4 Frequency
vs. Tuning Voltage, Vcc= +5V****Divide-by-4 Output Power
vs. Tuning Voltage, Vcc= +5V****Absolute Maximum Ratings**

Vcc1, Vcc2	+5.5 Vdc
Vtune	0 to +15V
Junction Temperature	135 °C
Continuous Pdiss (T=85 °C) (derate 37 mW/C above 85 °C)	1.85 W
Thermal Resistance (junction to ground paddle)	27 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C
ESD Sensitivity (HBM)	Class 1A

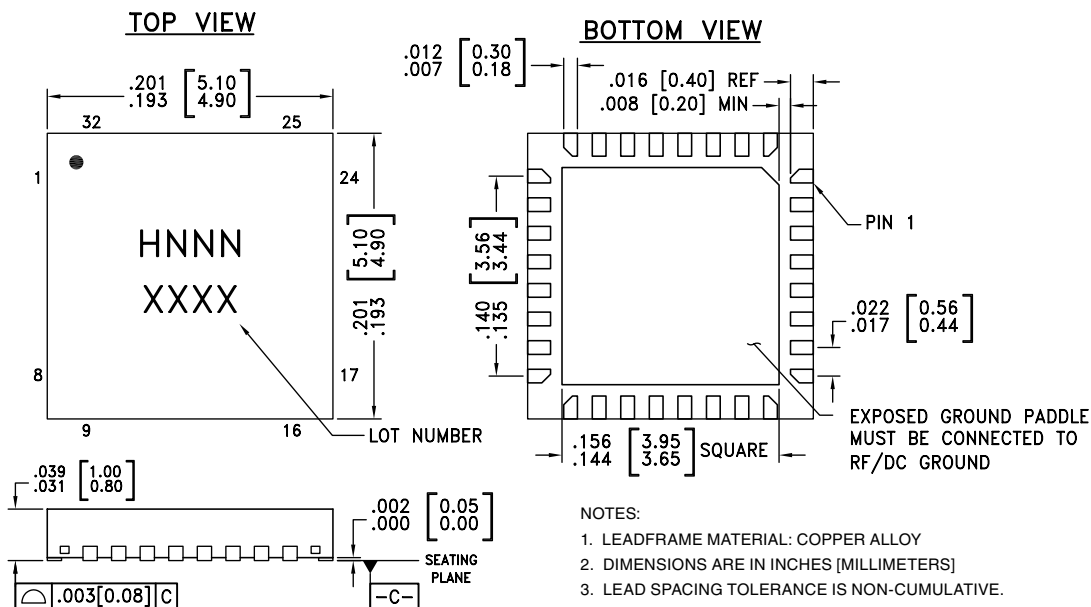
Typical Supply Current vs. Vcc

Vcc (V)	Icc (mA)
4.75	235
5.00	260
5.25	275

Note: VCO will operate over full voltage range shown above.

**ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS**

Outline Drawing



Package Information

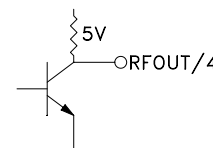
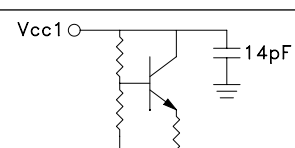
Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking ^[3]
HMC531LP5	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL3 ^[1]	H531 XXXX
HMC531LP5E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL3 ^[2]	H531 XXXX

[1] Max peak reflow temperature of 235 °C

[2] Max peak reflow temperature of 260 °C

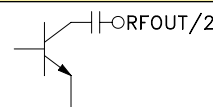
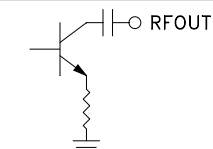
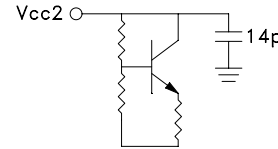
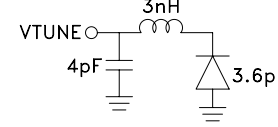
[3] 4-Digit lot number XXXX

Pin Descriptions

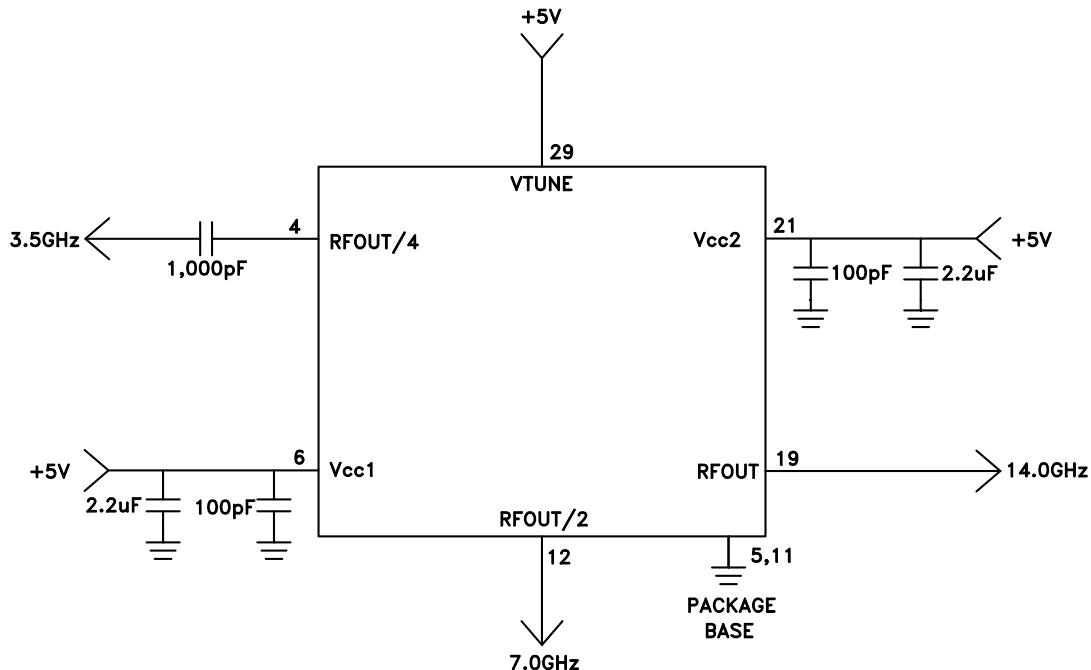
Pin Number	Function	Description	Interface Schematic
1 - 3, 7 - 10, 13 - 18, 20, 22 - 28, 30 - 32	N/C	No Connection. These pins may be connected to RF/DC ground. Performance will not be affected.	
4	RFOUT/4	Divide-by-4 Output.	
6	Vcc1	Supply Voltage for prescaler. If prescaler is not required, this pin may be left open to conserve 65 mA of current.	

MMIC VCO w/ HALF FREQUENCY OUTPUT & DIVIDE-BY-4, 13.6 - 14.9 GHz

Pin Descriptions

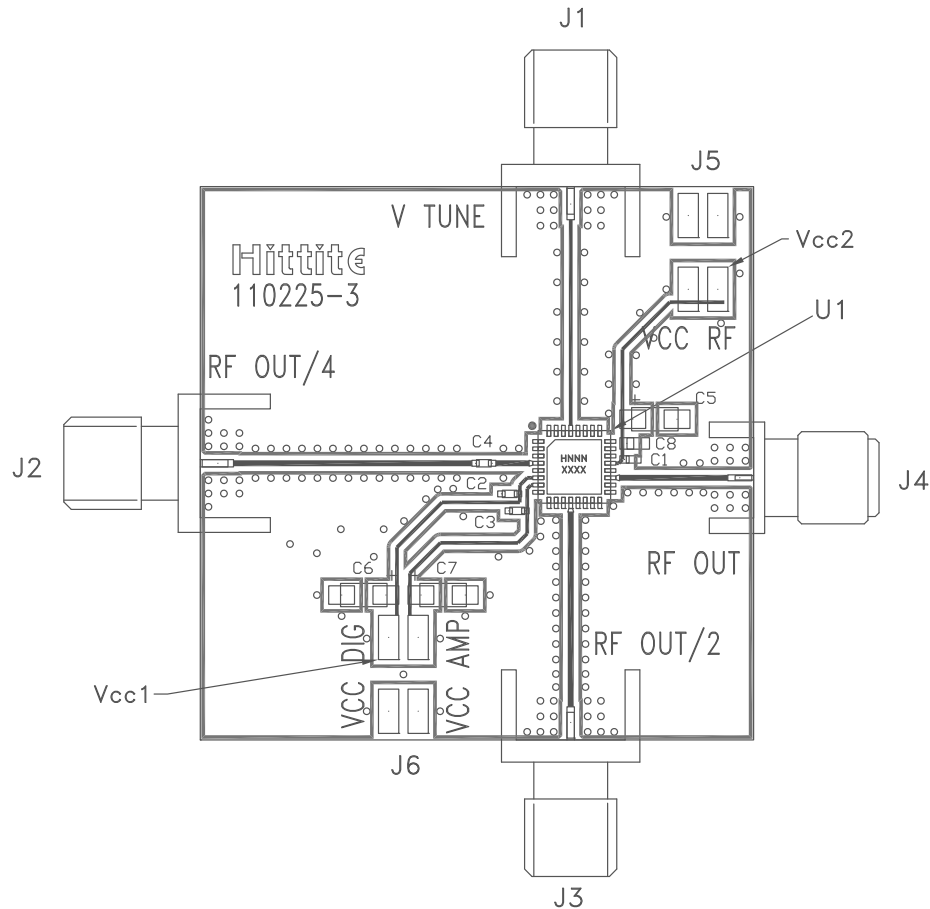
Pin Number	Function	Description	Interface Schematic
12	RFOUT/2	Half frequency output (AC coupled).	
19	RF OUT	RF output (AC coupled).	
21	Vcc2	Supply Voltage, +5V	
29	VTUNE	Control Voltage and Modulation Input. Modulation bandwidth dependent on drive source impedance. See "Determining the FM Bandwidth of a Wideband Varactor Tuned VCO" application note.	
5, 11 Paddle	GND	Package bottom has an exposed metal paddle that must be connected to RF/DC ground.	

Typical Application Circuit



MMIC VCO w/ HALF FREQUENCY OUTPUT & DIVIDE-BY-4, 13.6 - 14.9 GHz

Evaluation PCB



List of Materials for Evaluation PCB 110227 [1]

Item	Description
J1 - J4	PCB Mount SMA RF Connector
J5 - J6	2 mm DC Header
C1 - C3	100 pF Capacitor, 0402 Pkg.
C4	1,000 pF Capacitor, 0402 Pkg.
C5 - C7	2.2 μ F Tantalum Capacitor
U1	HMC531LP5(E) VCO
PCB [2]	110225 Eval Board

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Arlon 25FR

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and backside ground paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.

Данный компонент на территории Российской Федерации

Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:

moschip.ru

moschip.ru_4

moschip.ru_6

moschip.ru_9